

## Amendments to the Harmonized System Explanatory Notes – HS Committee 72<sup>nd</sup> Session

The following list contains the decisions taken by the Harmonized System Committee (**72<sup>nd</sup> Session – September 2023**) concerning amendments to the Harmonized System Explanatory Notes, applicable as of 1 December 2023. This publication will be updated regularly.

The Harmonized System Explanatory Notes are published by WCO in 5 volumes (**2022 edition**) and reflect the official interpretation of the Harmonized Commodity Description and Coding System. They also contain the text of the Subheading Explanatory Notes indicating the scope and content of certain of the Harmonized System Subheadings. The Explanatory Notes are available in English and French, the two official languages of the WCO, and can be ordered directly (see “Bookshop” on this Web site). They are also available on-line.

The amendments listed below are reproduced in the order of the current pages concerned and will be incorporated into the aforementioned WCO publications in due time by replacing the pages affected by the amendments made.

### **Advice**

Parties seeking to import or export merchandise covered by a decision are advised to verify the implementation of the decision by the importing or exporting country, as the case may be.

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AMENDMENTS TO THE EXPLANATORY NOTES

Heading 73.08.

Page XV-7308-1. Third paragraph.

French text only.

CHAPTER 85.

Heading 85.41.

Part (A). Second and third paragraphs. Page XVI-8541-1.

Delete and substitute :

“The operation of the devices of this group is based on the electronic properties of certain “semiconductor” materials (which are relevant for e.g., diodes and transistors) or, for the purpose of semiconductor-based transducers, on their semiconductor properties including physical (e.g., mechanical, thermal), electrical, optical and chemical properties.

The main characteristics of these semiconductor materials is that at room temperature their resistivity lies in the range between that of conductors (metals) and that of insulators. They consist, for instance, of certain ores (e.g., crystal galena), tetravalent chemical elements (germanium, silicon, etc.) or combinations of chemical elements (e.g., trivalent and pentavalent elements, such as gallium arsenide, indium antimonide).”

Part (A). Item (III). Sixth paragraph. Page XVI-8541-3.

Delete and substitute :

“The materials used in semiconductor-based transducers include e.g., Silicon (Si), Germanium (Ge), Carbon (C), Silicon Germanium (SiGe), Silicon Carbide (SiC), Gallium Nitride (GaN), Gallium Arsenide (GaAs), Indium Gallium Arsenide InGaAs, Indium Antimonide (InSb), Gallium Phosphide (GaP), Indium Phosphide (InP), Tin Telluride (SnTe), Zinc Oxide (ZnO) and Gallium Oxide (Ga<sub>2</sub>O<sub>3</sub>).”